• Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D²PAK (TO-263AB) package)

150 °C

ITO-220AB, D²PAK (TO-263AB)

Single

ITO-220AB

 Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for ITO-220AB package)

 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: ITO-220AB, D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

VF20100-M3 suffix meets JESD 201 class 1A whisker test

VI20100-M3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	VF20100S	VB20100S	UNIT	
Max. repetitive peak reverse voltage	V _{RRM}	100		V	
Max. average forward rectified current (fig. 1)	I _{F(AV)}	20		А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	2	50	А	
Non-repetitive avalanche energy at $T_J = 25$ °C, L = 60 mH	E _{AS}	210		mJ	
Peak repetitive reverse current at $t_p = 2 \ \mu s$, 1 kHz, $T_J = 38 \ ^{\circ}C \pm 2 \ ^{\circ}C$	I _{RRM}	1	.0	A	
Voltage rate of change (rated V _R)	dV/dt	10 000		V/µs	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC} 1500		V		
Operating junction and storage temperature range	T _J , T _{STG}	-40 to	o +150	°C	

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- · High efficiency operation
- Low thermal resistance

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High Voltage TMBS[®] (Trench MOS Barrier Schottky) Rectifier Ultra Low $V_F = 0.446$ V at $I_F = 5$ A

NC	123
VB20100S	VF20100S
	PIN 1 O PIN 2 PIN 3 O
PRIMARY CHARACTE	RISTICS
I _{F(AV)}	20 A
V _{RRM}	100 V
I _{FSM}	250 A
V_F at $I_F = 20$ A	0.69 V

VF20100S-M3, VB20100S-M3

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D²PAK (TO-263AB)

T_J max.

Package

Circuit configuration



RoHS

COMPLIANT HALOGEN

FREE



VF20100S-M3, VB20100S-M3



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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CO	TEST CONDITIONS SYMB		TYP.	MAX.	UNIT	
Breakdown voltage	I _R = 10 mA	T _A = 25 °C	V _{BR}	105 (min.)	-	V	
Instantaneous forward voltage	I _F = 5 A	T _A = 25 °C	- V _F (1)	0.51	-	V	
	I _F = 10 A			0.60	-		
	I _F = 20 A			0.79	0.90		
	I _F = 5 A	T _A = 125 °C		0.45	-		
	I _F = 10 A			0.53	-		
	I _F = 20 A			0.69	0.76		
Reverse current	V _R = 70 V	T _A = 25 °C	I _R ⁽²⁾	17	-	μA	
	$\mathbf{v}_{\mathrm{R}} = 70$ V	T _A = 125 °C		7	-	mA	
	V _R = 100 V	T _A = 25 °C		70	500	μA	
	v _R = 100 v	T _A = 125 °C]	14	30	mA	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	VF20100S	VB20100S	UNIT		
Typical thermal resistance	$R_{ extsf{ heta}JC}$	4.0	2.0	°C/W		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
ITO-220AB	VF20100S-M3/4W	1.75	4W	50/tube	Tube	
D ² PAK (TO-263AB)	VB20100S-M3/4W	1.37	4W	50/tube	Tube	
D ² PAK (TO-263AB)	VB20100S-M3/8W	1.37	8W	800/reel	Tape and reel	

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

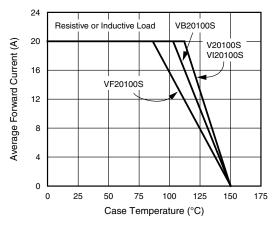


Fig. 1 - Maximum Forward Current Derating Curve

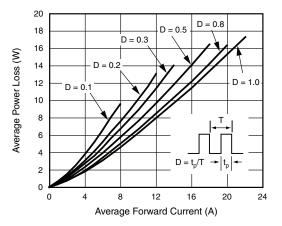


Fig. 2 - Forward Power Loss Characteristics

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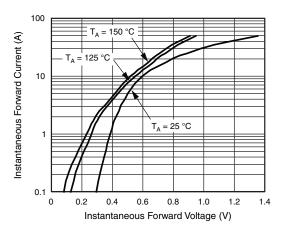


Fig. 3 - Typical Instantaneous Forward Characteristics

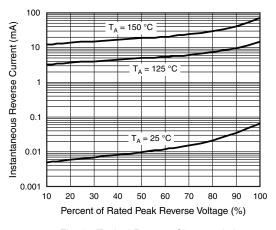


Fig. 4 - Typical Reverse Characteristics

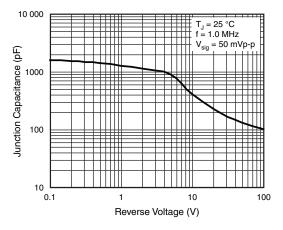


Fig. 5 - Typical Junction Capacitance

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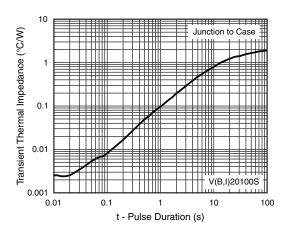


Fig. 6 - Typical Transient Thermal Impedance

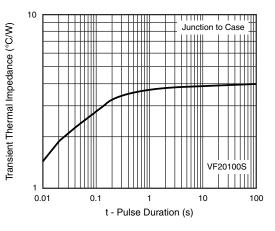


Fig. 7 - Typical Transient Thermal Impedance

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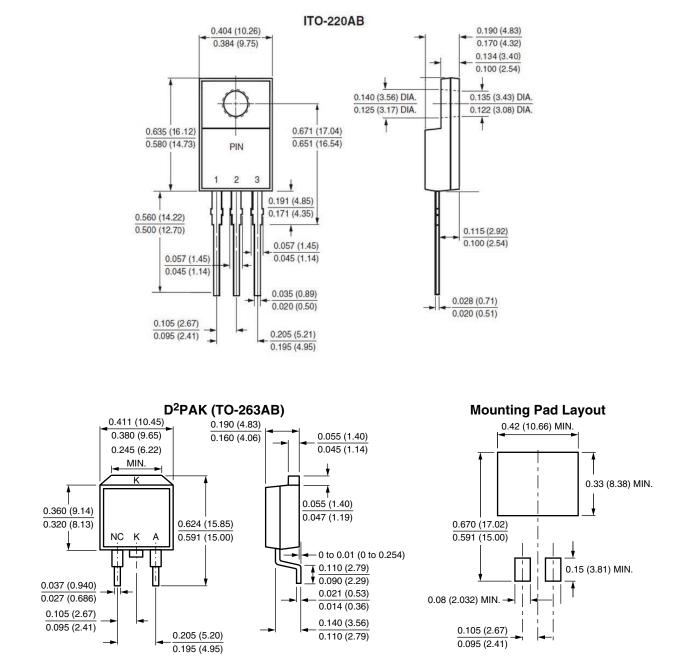
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VF20100S-M3, VB20100S-M3

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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